NSN 5961-01-343-8873

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View Online at https://aerobasegroup.com/nsn/5961-01-343-8873 **Inclosure Material:** Metal **Overall Length:** 0.070 inches **Terminal Length:** 0.160 inches **Overall Diameter:** Between 0.099 inches and 0.101 inches **Function For Which Designed:** Microwave **Internal Configuration:** Junction contact **Mounting Method: Terminal Features Provided:** Hermetically sealed case and electrostatic sensitive **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 35.0 collector to base voltage/static/emitter open and 18.0 collector to emitter voltage/static/base open and 3.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 100.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 290.0 milliwatts small-signal input power, common-collector **Transfer Ratio:** 30.0 static forward current transfer ratio, common-emitter and 200.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Special Features:** 9hazardous material: beryllium oxide: handling procedures: do not polish, cross-section, grind or otherwise open component without taking adequate safeguards: materials contained within may be injurious to your health; junction pattern arrangement: npn **Terminal Type And Quantity:** 4 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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No